**Vishay Semiconductors** 

High Performance Schottky Rectifier, 1 A



www.vishay.com



SMB (DO-214AA)

PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	1 A					
V <sub>R</sub>	100 V					
V <sub>F</sub> at I <sub>F</sub>	0.59 V					
I <sub>RM</sub>	1 mA at 125 °C					
T <sub>J</sub> max.	175 °C					
Diode variation	Single die					
E <sub>AS</sub>	1.0 mJ					
Package	SMB (DO-214AA)					
Circuit configuration	Single					

### **FEATURES**

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

The VS-10BQ100HM3 surface-mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL CHARACTERISTICS VALUES U						
I <sub>F(AV)</sub>	Rectangular waveform	1	А			
V <sub>RRM</sub>		100	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	780	Α			
V <sub>F</sub>	1.0 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.59	V			
TJ	Range	-55 to +175	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-10BQ100HM3	UNITS			
Maximum DC reverse voltage	V <sub>R</sub>	100	N/			
Maximum working peak reverse voltage	V <sub>RWM</sub>	100	v			

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDI	TEST CONDITIONS			
Maximum average forward current	I <sub>F(AV)</sub>	50 % duty cycle at $T_L$ = 143 °C, rectangular waveform		1.0	А	
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated	780	A	
		10 ms sine or 6 ms rect. pulse	load condition and with rated V <sub>RRM</sub> applied	38		
Non-repetitive avalanche energy	E <sub>AS</sub>	$T_J = 25 \text{ °C}, I_{AS} = 0.5 \text{ A}, L = 8 \text{ mH}$ 1.0		1.0	mJ	
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical 0.5		А		

RoHS COMPLIANT HALOGEN

FREE



www.vishay.com

## Vishay Semiconductors

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST C	VALUES	UNITS	
	V <sub>FM</sub> <sup>(1)</sup>	1 A	T <sub>.1</sub> = 25 °C	0.75	V
Maximum forward voltage drop See fig. 1		2 A	1j=25 C	0.82	
		1 A	T <sub>.1</sub> = 125 °C	0.59	
		2 A	1j=125 0	0.65	
Maximum reverse leakage current	l	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated V <sub>B</sub>	0.5	mA
See fig. 2	I <sub>RM</sub>	T <sub>J</sub> = 125 °C	VR - naleu VR	1	
Typical junction capacitance	CT	$V_R = 5 V_{DC}$ , (test signal ra	65	pF	
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body 2.0 nH			nH
Maximum voltage rate of charge	dV/dt	Rated V <sub>R</sub> 10 000 V/μs			V/µs

Note

<sup>(1)</sup> Pulse width = 300  $\mu$ s, duty cycle = 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		-55 to +175	°C	
Maximum thermal resistance, junction to lead	R <sub>thJL</sub> <sup>(2)</sup>	DC operation	36	°C/W	
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>		80	C/W	
A payovimeto veight			0.10	g	
Approximate weight			0.003	oz.	
Marking device		Case style SMB (DO-214AA)	1	J	

Notes

(1)

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink

(2) Mounted 1" square PCB



# **VS-10BQ100HM3**

### **Vishay Semiconductors**

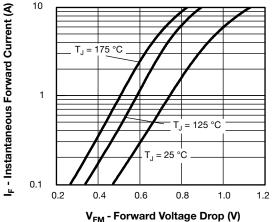


Fig. 1 - Maximum Forward Voltage Drop Characteristics

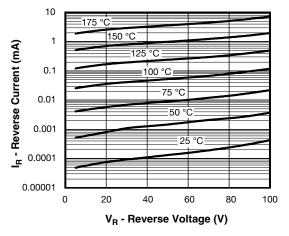


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

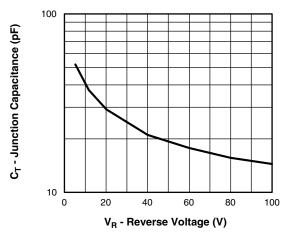


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

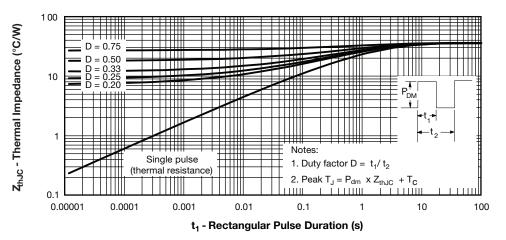


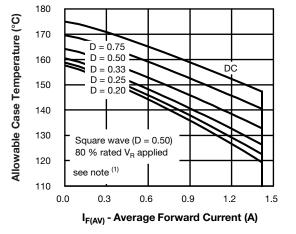
Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)

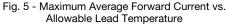
Revision: 23-Apr-2019 Document Number: 95725 3 For technical questions within your region: DiodesAmericas@vishay.com, Diodes Asia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



## VS-10BQ100HM3

**Vishay Semiconductors** 





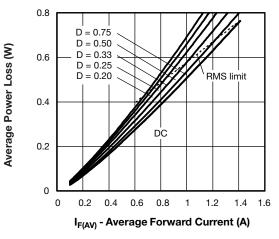


Fig. 6 - Maximum Average Forward Dissipation vs. Average Forward Current

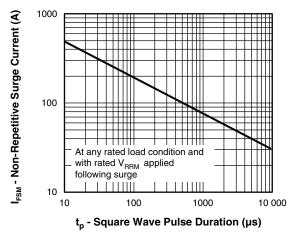
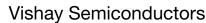


Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

#### Note

- <sup>(1)</sup> Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ;
- $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ x \ \mathsf{V_{FM}} \ at \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ x \ \mathsf{I}_{\mathsf{R}} \ (1 \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ at \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$



www.vishay.com

### **ORDERING INFORMATION TABLE**

Device code	VS-	10	в	Q	100	Н	М3	
	1	2	3	4	5	6	7	
	1	- Visl	nay Serr	nicondu	ctors pr	oduct		
	2	- Cur	Current rating					
	3	- B=	B = SMB (DO-214AA)					
	4	- Q =	Q = Schottky "Q" series					
	5	- Vol	Voltage rating (100 = 100 V)					
	6	• H=	H = AEC-Q101 qualified					
	7	- Env	vironmer	ntal digit	::			
		М3	M3 = halogen-free, RoHS compliant, and terminations lead (Pb)-fr					

**ORDERING INFORMATION** (Example) **PREFERRED P/N** PREFERRED PACKAGE CODE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION VS-10BQ100HM3/5BT 5BT 3200 13" diameter plastic tape and reel

LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95401				
Part marking information	www.vishay.com/doc?95403			
Packaging information	www.vishay.com/doc?95404			
SPICE model	www.vishay.com/doc?96603			

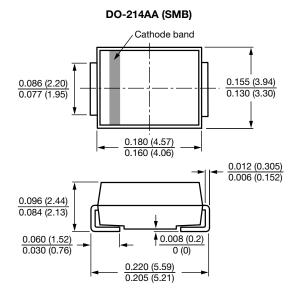


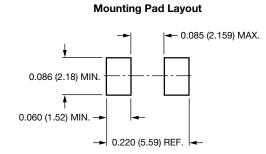
## **Outline Dimensions**

**Vishay Semiconductors** 

**SMB** 

### **DIMENSIONS** in inches (millimeters)







Vishay

## Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.